

MBR1040DFCT THRU MBR10200DFCT
Schottky Barrier Rectifiers

Voltage: 40~200 Volts

Current: 10 Amperes

Package: TO-220F

Features

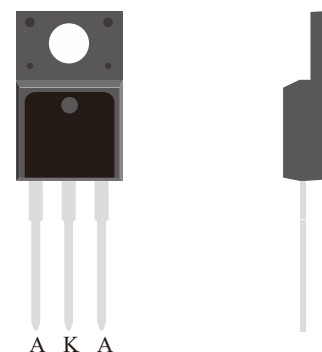
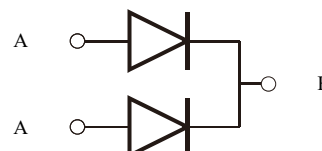
- NH'S Plane Schottky Barrier Chip Technology
- Low Forward Voltage Drop For High Efficiency
- Low Power Loss For High Reliability
- High Frequency Switching Speed

Mechanical Data

- **Case:** Molded With UL-94 Class V-0 Recognized, RoHS-Compliant
- **Polarity:** Look At The Diagram And Polarity On The Right
- **Terminals:** Tin Plated Leads, Solderable Per J-STD-002 And JESD22-B102

Typical Applications

- Switch Mode Power Supplies (SMPS)
- Fast Chargers
- LED Driver And Monitor Lighting
- Automotive Electronics And Charging Posts

Diagram:

Polarity:


Single Phase, Half Wave, 60Hz, Resistive Or Inductive Load. For Capacitive Load, Derate Current By 20%

Maximum Ratings (Ta=25°C Unless Otherwise Specified)

Parameter	Test Conditions	Symbol	MBR10 40DFCT	MBR10 45DFCT	MBR10 60DFCT	MBR10 80DFCT	MBR10 100DFCT	MBR10 150DFCT	MBR10 200DFCT	Unit
Maximum Repetitive Peak Reverse Voltage		V_{RRM}	40	45	60	80	100	150	200	V
Maximum RMS Voltage		V_{RMS}	28	32	42	56	70	105	140	V
Maximum DC Blocking Voltage		V_{DC}	40	45	60	80	100	150	200	V
Maximum Average Forward Rectified Current	Per Diode Total device	$I_{F(AV)}$	5 10							A
Peak Forward Surge Current Per Diode	8.3ms Single Half Sine-wave Superimposed On Rate Load	I_{FSM}	120							A
Current Squared Time Per Diode	$t < 8.3ms$	I^2t	59.8							A ² sec
Maximum Mounting Torque	M3 screw	T_{MM}	1.1							N.m

Electrical Characteristics (Ta=25°C Unless Otherwise Specified)

Parameter	Test Conditions	Symbol	MBR10 40DFCT	MBR10 45DFCT	MBR10 60DFCT	MBR10 80DFCT	MBR10 100DFCT	MBR10 150DFCT	MBR10 200DFCT	Unit
Instantaneous Forward Voltage Per Diode	$I_F = 5.0 A$	V_F	0.55	0.70	0.85	0.90				V
Maximum DC Reverse Current at Rated DC Blocking Voltage	Ta=25°C, $V_R = V_{RRM}$ Ta=110°C, $V_R = V_{RRM} * 80\%$	I_{RRM}	100 10	80 8	50 5	10 3				uA mA
Typical Junction Capacitance Per Diode	4 V, 1MHz	C_J	350	280	220	100				pF

Thermal Characteristics (Ta=25°C Unless Otherwise Specified)

Parameter	Test Conditions	Symbol	MBR10 40DFCT	MBR10 45DFCT	MBR10 60DFCT	MBR10 80DFCT	MBR10 100DFCT	MBR10 150DFCT	MBR10 200DFCT	Unit
Operating Junction Temperature Range		T _J	-55~150						-55~175	℃
Storage Temperature Range		T _{STD}	-55~150						-55~175	
Thermal Resistance Junction To Ambient With Steady-State	Still Air Environment With Ta=25℃	R _{0JA}	62.5							℃/W
Thermal Resistance Junction-Case With Steady-State	Device Mounted On 75mm x 45mm x 2.5mm Alu. Heat.	R _{0JC}	3.5							

Notes: 1. Pulse Test: 300 Us Pulse Width, 1% Duty Cycle

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Typical Characteristics Curves

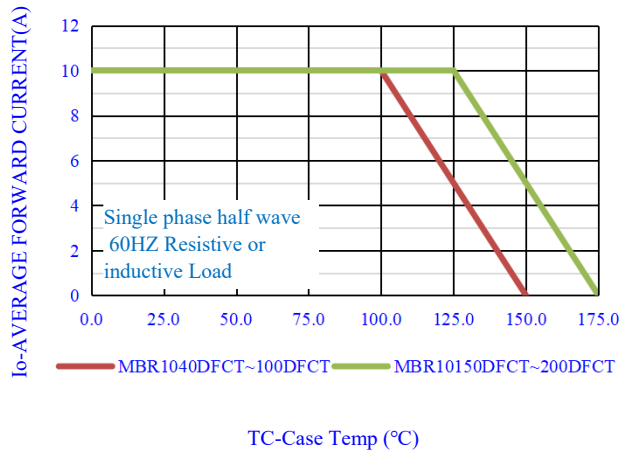


Fig.1-FORWARD CURRENT DERATING CURVE

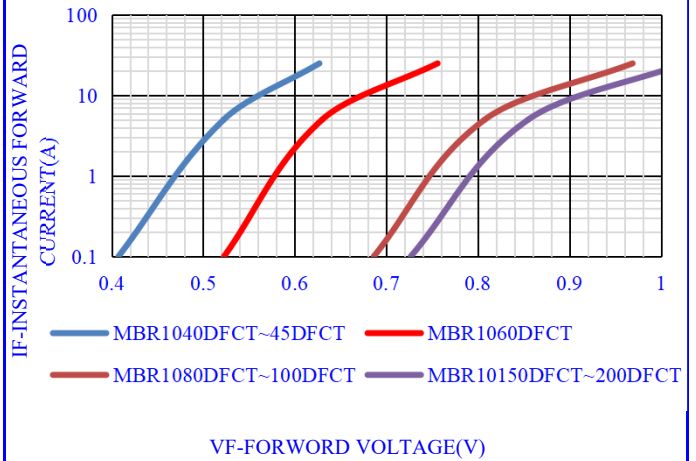


Fig.2- TYPICAL INSTANTANEOUS FORWARD

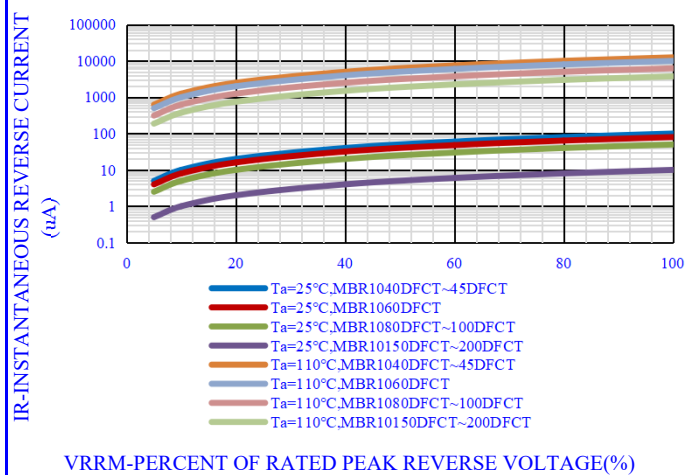


Fig.3- TYPICAL REVERSE CHARACTERISTICS

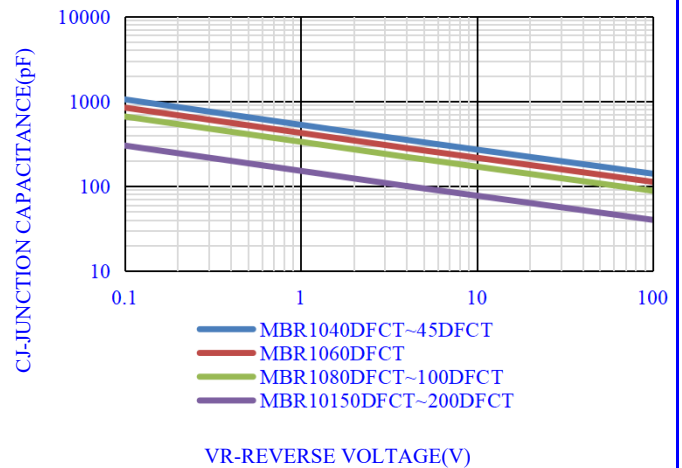


Fig.4- TYPICAL JUNCTION CAPACITANCE

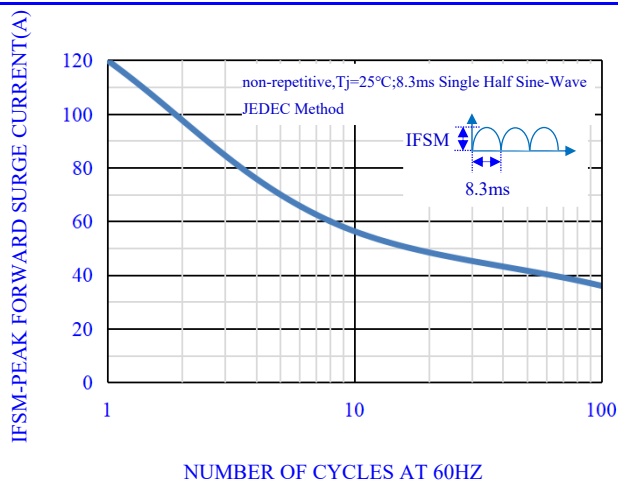


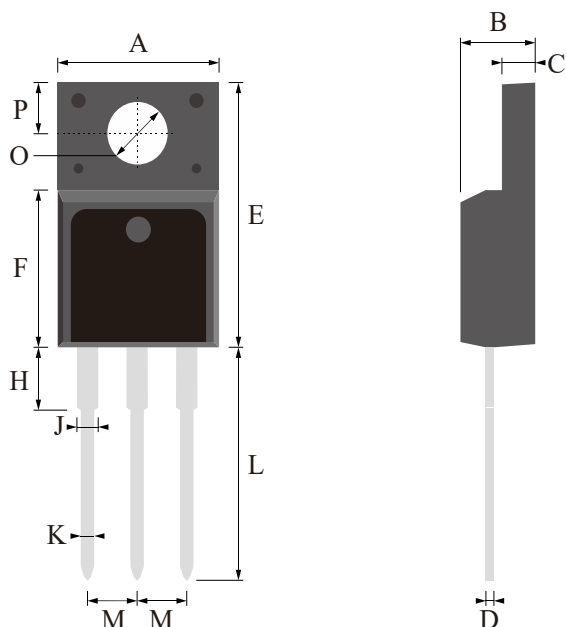
Fig.5-MAX. NON-REPETITIVE SURGE CURRENT

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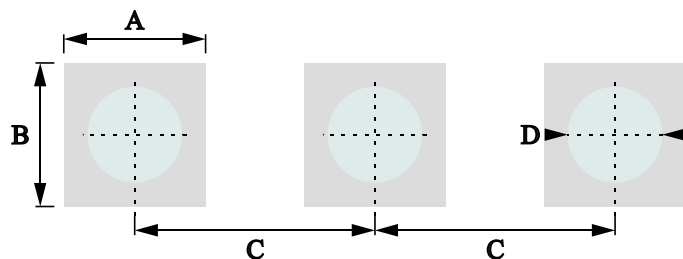
OUTLINE DRAWINGS



TO-220F

OUTLINE DIMENSIONS						
Dim.	Milimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	9.25	-	10.75	0.3642	-	0.4232
B	2.30	-	2.90	0.0906	-	0.1142
C	4.20	-	5.20	0.1654	-	0.2047
D	0.35	-	0.75	0.0138	-	0.0295
E	14.80	-	16.80	0.5827	-	0.6614
F	8.25	-	9.75	0.3248	-	0.3839
L	12.15	-	14.15	0.4783	-	0.5571
H	2.40	-	3.00	0.0945	-	0.1181
J	1.10	-	1.50	0.0433	-	0.0591
K	0.60	-	1.00	0.0236	-	0.0394
M	2.20	-	3.00	0.0866	-	0.1181
O	2.70	-	3.50	0.1063	-	0.1378
P	2.25	-	2.85	0.0886	-	0.1122

RECOMMEDND LAYOUT DRAWINGS



TO-220F

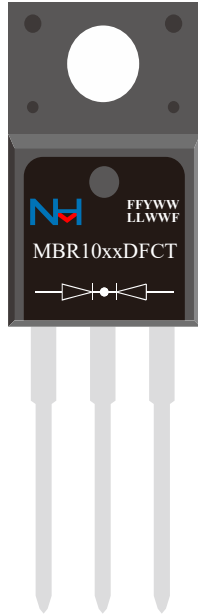
OUTLINE DIMENSIONS						
Dim.	Milimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	-	1.60	-	-	0.0630	-
B	-	1.60	-	-	0.0630	-
C	-	2.54	-	-	0.1000	-
D	-	1.00	-	-	0.0394	-

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MARKING



MARKING INSTRUCTION

NH=Niuhan Trademark
FF=Product Line Code,According To Actual Changes
YWW=Date Code,According To Actual Changes
LLWWF=Inernal Code,According To Actual Changes
MBR10xxDFCT=Model,x=xx=40,45,60,80,100,150,200

PACKING INFORMATION

Package Type	Package Code	Product Weight Approx(g/Pcs)	Package Method	Quantity (Pcs/Min. Pack.)	Quantity (Pcs/Inner Box)	Quantity (Pcs/Carton)
TO-220F	P1	2.048	Tube	50	1000	5000

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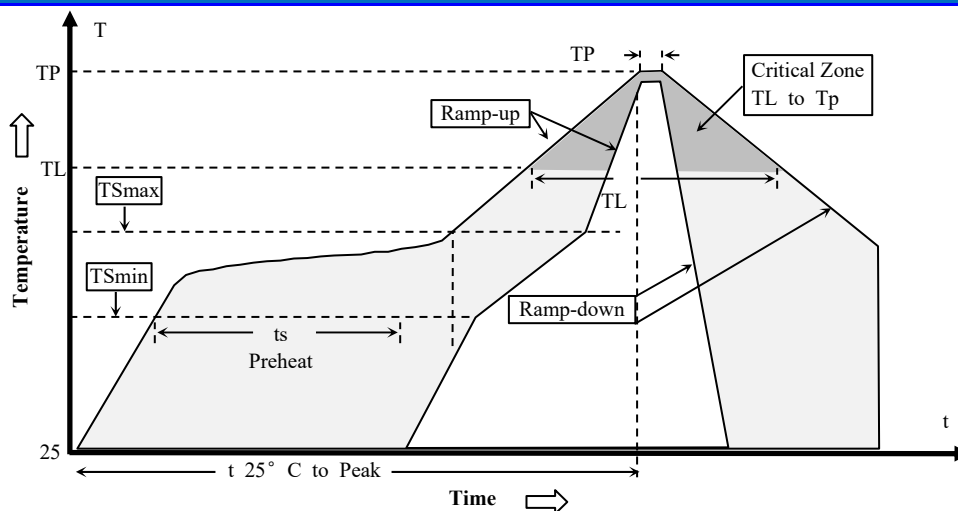
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Recommended wave soldering condition

Product	Peak Temperature	Soldering Time
Pb-free devices	260 +0/-5 °C	5 +1/-1 seconds

Recommended temperature profile for IR reflow



Profile feature	Sn-Pb eutectic Assembly	Pb-free Assembly
Average ramp-up rate (T _{smax} to T _p)	3°C/second max.	3°C/second max.
Preheat -Temperature Min(T _S min) -Temperature Max(T _S max) -Time(t _s min to t _s max)	100°C 150°C 60-120 seconds	150°C 200°C 60-180 seconds
Time maintained above: -Temperature (T _L) - Time (t _L)	183°C 60-150 seconds	217°C 60-150 seconds
Peak Temperature(T _P)	240 +0/-5 °C	260 +0/-5 °C
Time within 5°C of actual peak temperature(tp)	10-30 seconds	20-40 seconds
Ramp down rate	6°C/second max.	6°C/second max.
Time 25 °C to peak temperature	6 minutes max.	8 minutes max.

Note : All temperatures refer to topside of the package, measured on the package body surface.

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